X9C102, X9C103, X9C104, X9C503
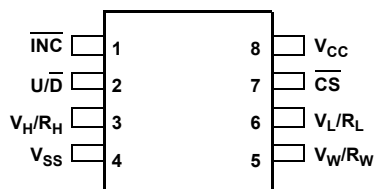### Digitally Controlled Potentiometer (XDCP™)

The [X9C102](), [X9C103](), [X9C104](), [X9C503]() are digitally controlled (XDCP) potentiometers. The device consists of a resistor array, wiper switches, a control section, and nonvolatile memory. The wiper position is controlled by a three-wire interface.

The potentiometer is implemented by a resistor array composed of 99 resistive elements and a wiper switching network. Between each element and at either end are tap points accessible to the wiper terminal. The position of the wiper element is controlled by the $\overline{CS}$, U/$\overline{D}$, and $\overline{INC}$ inputs. The position of the wiper can be stored in non-volatile memory and then be recalled upon a subsequent power-up operation.

The device can be used as a three-terminal potentiometer or as a two-terminal variable resistor in a wide variety of applications ranging from control to signal processing to parameter adjustment.
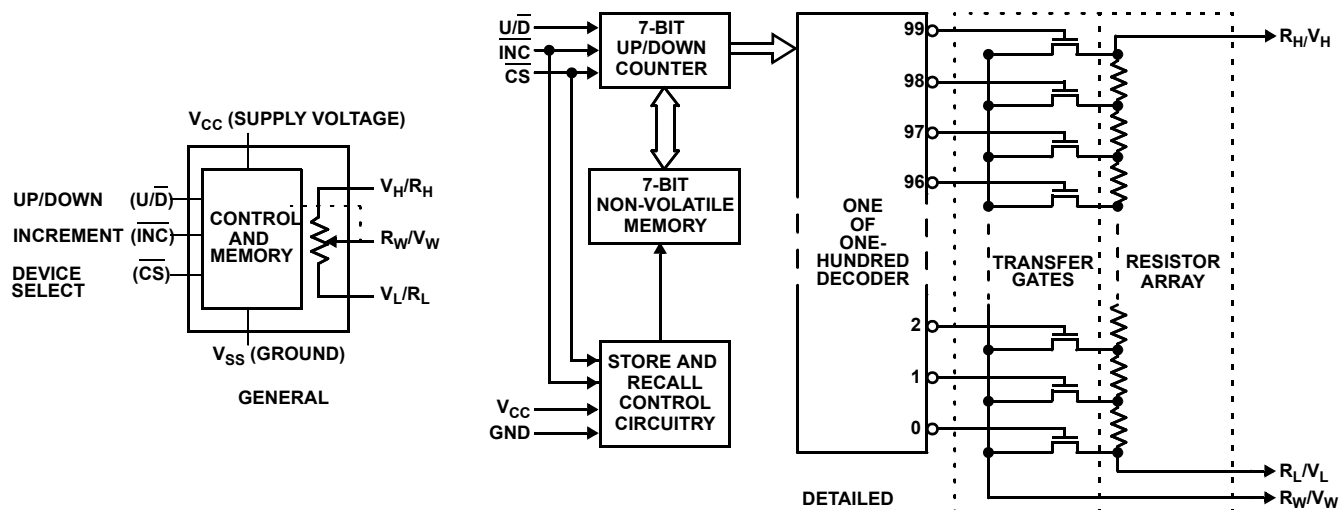
Features

- Solid-State Potentiometer

- Three-Wire Serial Interface

- 100 Wiper Tap Points
  - Wiper Position Stored in Non-volatile Memory and Recalled on Power-up

- 99 Resistive Elements
  - Temperature Compensated
  - End-to-End Resistance, ±20%
  - Terminal Voltages, ±5V

- Low Power CMOS
  - V_{CC} = 5V
  - Active Current, 3mA max.
  - Standby Current, 750µA max.

- High Reliability
  - Endurance, 100,000 Data Changes per Bit
  - Register Data Retention, 100 years

- X9C102 = 1kΩ

- X9C103 = 10kΩ

- X9C503 = 50kΩ

- X9C104 = 100kΩ

- Packages
  - 8 Ld SOIC
  - 8 Ld PDIP

- Pb-Free Available (RoHS Compliant)

Pinout

X9C102, X9C103, X9C104, X9C503
(8 LD SOIC, 8 LD PDIP)
TOP VIEW

Block Diagram

Ordering Information

PART NUMBER	PART MARKING	R_{TOTAL} (kΩ)	TEMP RANGE (°C)	PACKAGE (RoHS Compliant)	PACKAGE DWG. #
X9C102PZ (Notes 2, 3)	X9C102P Z	1	0 to +70	8 Ld PDIP	MDP0031
X9C102PIZ (Notes 2, 3)	X9C102P ZI		-40 to +85	8 Ld PDIP	MDP0031
X9C102SZ (Notes 1, 2)	X9C102S Z		0 to +70	8 Ld SOIC	M8.15E
X9C102SIZ (Notes 1, 2)	X9C102S ZI		-40 to +85	8 Ld SOIC	M8.15E
X9C103PZ (Notes 2, 3)	X9C103P Z	10	0 to +70	8 Ld PDIP	MDP0031
X9C103PIZ (Notes 2, 3)	X9C103P ZI		-40 to +85	8 Ld PDIP	MDP0031
X9C103SZ (Notes 1, 2)	X9C103S Z		0 to +70	8 Ld SOIC	M8.15
X9C103SIZ (Notes 1, 2)	X9C103S ZI		-40 to +85	8 Ld SOIC	M8.15
X9C503PZ (Notes 2, 3)	X9C503P Z	50	0 to +70	8 Ld PDIP	MDP0031
X9C503PIZ (Notes 2, 3)	X9C503P ZI		-40 to +85	8 Ld PDIP	MDP0031
X9C503SZ (Notes 1, 2)	X9C503S Z		0 to +70	8 Ld SOIC	M8.15E
X9C503SIZ (Notes 1, 2)	X9C503S ZI		-40 to +85	8 Ld SOIC	M8.15E
X9C104PIZ (Notes 2, 3)	X9C104P ZI	100	-40 to +85	8 Ld PDIP	MDP0031
X9C104SZ (Notes 1, 2)	X9C104S Z		0 to +70	8 Ld SOIC	M8.15E
X9C104SIZ (Notes 1, 2)	X9C104S ZI		-40 to +85	8 Ld SOIC	M8.15E

NOTES:

1. Add "T1" suffix for tape and reel. See TB347 for details about reel specifications.

2. These Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

3. Pb-free PDIPs can be used for through-hole wave solder processing only. They are not intended for use in Reflow solder processing applications.

Pin Descriptions

PIN NUMBER	PIN NAME	DESCRIPTION
1	$\overline{INC}$	**INCREMENT** The $\overline{INC}$ input is negative-edge triggered. Toggling $\overline{INC}$ will move the wiper and either increment or decrement the counter in the direction indicated by the logic level on the $U/\overline{D}$ input.
2	$U/\overline{D}$	**UP/DOWN** The $U/\overline{D}$ input controls the direction of the wiper movement and whether the counter is incremented or decremented.
3	V_H/R_H	**V_H/R_H** The high (V_H/R_H) terminals of the X9C102, X9C103, X9C104, X9C503 are equivalent to the fixed terminals of a mechanical potentiometer. The minimum voltage is -5V and the maximum is +5V. The terminology of V_H/R_H and V_L/R_L references the relative position of the terminal in relation to wiper movement direction selected by the $U/\overline{D}$ input and not the voltage potential on the terminal.
4	V_{SS}	**V_{SS}**
5	V_W/R_W	**V_W/R_W** V_W/R_W is the wiper terminal and is equivalent to the movable terminal of a mechanical potentiometer. The position of the wiper within the array is determined by the control inputs. The wiper terminal series resistance is typically 40Ω.
6	R_L/V_L	**R_L/V_L** The low (V_L/R_L) terminals of the X9C102, X9C103, X9C104, X9C503 are equivalent to the fixed terminals of a mechanical potentiometer. The minimum voltage is -5V and the maximum is +5V. The terminology of V_H/R_H and V_L/R_L references the relative position of the terminal in relation to wiper movement direction selected by the $U/\overline{D}$ input and not the voltage potential on the terminal.
7	$\overline{CS}$	**$\overline{CS}$** The device is selected when the $\overline{CS}$ input is LOW. The current counter value is stored in non-volatile memory when $\overline{CS}$ is returned HIGH while the $\overline{INC}$ input is also HIGH. After the store operation is complete the X9C102, X9C103, X9C104, X9C503 device will be placed in the low power standby mode until the device is selected once again.
8	V_{CC}	**V_{CC}**

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Absolute Maximum Ratings

Voltage on $\overline{CS}$, $\overline{INC}$, U/$\overline{D}$ and V_{CC} with Respect to V_{SS} . -1V to +7V
Voltage on V_H/R_H and V_L/R_L Referenced to V_{SS}. . . . . . . -8V to +8V
$\Delta V = |V_H/R_H - V_L/R_L|$
   X9C102 . . . . .4V
   X9C103, X9C104, and X9C503 . . . . .10V
I_W (10s) 8.8mA
Power Rating
   X9C102 . . . . .16mW
   X9C103 X0C104, and X9C503 . . . . .10mW

Thermal Information

Temperature Under Bias . . . .-65°C to +135°C
Storage Temperature . . . .-65°C to +150°C
Pb-Free Reflow Profile. TB493
*Pb-free PDIPs can be used for through-hole wave solder processing only. They are not intended for use in Reflow solder processing applications.

Recommended Operating Conditions

Commercial Temperature Range. . . . . 0°C to +70°C
Industrial Temperature Range . . . .-40°C to +85°C
Supply Voltage Range (V_{CC}) . . . . 5V ±10%

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

Electrical Specifications   Over recommended operating conditions unless otherwise stated.

| SYMBOL	PARAMETER	TEST CONDITIONS	MIN	TYP (Note 7)	MAX	UNIT
POTENTIOMETER CHARACTERISTICS						
R_{TOTAL}	End-to-End Resistance Variation		-20		+20	%
$V_{VH/RH}$	V_H Terminal Voltage		-5		+5	V
$V_{VL/RL}$	V_L Terminal Voltage		-5		+5	V
I_W	Wiper Current		-4.4		4.4	mA
R_W	Wiper Resistance	Wiper Current = ±1mA		40	100	Ω
	Resistor Noise (Note 8)	Ref 1kHz		-120		dBV
	Charge Pump Noise (Note 8)	@ 850kHz		20		mV$_{RMS}$
	Resolution			1		%
	Absolute Linearity (Note 4)	$V_{W(n)(actual)} - V_{W(n)(EXPECTED)}$	-1		+1	MI (Note 6)
	Relative Linearity (Note 5)	$V_{W(n+1)(ACTUAL)} - [V_{W(n)+MI}]$	-0.2		+0.2	MI (Note 6)
	R_{TOTAL} Temperature Coefficient	X9C103, X9C503, X9C104		±300 (Note 8)		ppm/°C
	R_{TOTAL} Temperature Coefficient	X9C102		±600 (Note 8)		ppm/°C
	Ratiometric Temperature Coefficient			±20		ppm/°C
$C_H/C_L/C_W$ (Note 8)	Potentiometer Capacitances	See "Circuit #3 SPICE Macro Model" on page 5.		10/10/25		pF
DC OPERATING CHARACTERISTICS						
I_{CC}	V_{CC} Active Current	$\overline{CS} = V_{IL}$, U/$\overline{D} = V_{IL}$ or V_{IH} and $\overline{INC}$ = 0.4V to 2.4V at Max t_{CYC}		1	3	mA
I_{SB}	Standby Supply Current	$\overline{CS} = V_{CC}$ - 0.3V, U/$\overline{D}$ and $\overline{INC} = V_{SS}$ or V_{CC} - 0.3V		200	750	µA
I_{LI}	$\overline{CS}$, $\overline{INC}$, U/$\overline{D}$ Input Leakage Current	$V_{IN} = V_{SS}$ to V_{CC}			±10	µA
V_{IH}	$\overline{CS}$, $\overline{INC}$, U/$\overline{D}$ input HIGH Voltage		2			V
V_{IL}	$\overline{CS}$, $\overline{INC}$, U/$\overline{D}$ input LOW Voltage				0.8	V
C_{IN}	$\overline{CS}$, $\overline{INC}$, U/$\overline{D}$ Input Capacitance (Note 8)	V_{CC} = 5V, $V_{IN} = V_{SS}$, T_A = +25°C, f = 1MHz		10		pF

Electrical Specifications   Over recommended operating conditions unless otherwise stated. **(Continued)**

SYMBOL	PARAMETER	TEST CONDITIONS	MIN	TYP (Note 7)	MAX	UNIT
				LIMITS		
AC OPERATION CHARACTERISTICS						
t_{CI}	$\overline{CS}$ to $\overline{INC}$ Setup		100			ns
t_{ID}	$\overline{INC}$ HIGH to U/$\overline{D}$ Change		100			ns
t_{DI}	U/$\overline{D}$ to $\overline{INC}$ Setup		2.9			µs
t_{IL}	$\overline{INC}$ LOW Period		1			µs
t_{IH}	$\overline{INC}$ HIGH Period		1			µs
t_{IC}	$\overline{INC}$ Inactive to $\overline{CS}$ Inactive		1			µs
t_{CPH}	$\overline{CS}$ Deselect Time (STORE)		20			ms
t_{CPH}	$\overline{CS}$ Deselect Time (NO STORE)		100			ns
t_{IW} (5)	$\overline{INC}$ to $V_{W/RW}$ Change			100		µs
t_{CYC}	$\overline{INC}$ Cycle Time		2			µs
t_{CYC}	$\overline{INC}$ Input Rise and Fall Time				500	µs
t_R, t_F	Power-up to Wiper Stable (Note 8)			500		µs
t_{PU}	V_{CC} Power-up Rate (Note 8)		0.2		50	V/ms

NOTES:

4. Absolute linearity is utilized to determine actual wiper voltage vs expected voltage = $[V_{W(n)(actual)} - V_{W(n)(expected)}] = \pm1$ MI Maximum.

5. Relative linearity is a measure of the error in step size between taps = $V_{W(n + 1)} - [V_{W(n) + MI}] = +0.2$ MI.

6. 1 MI = Minimum Increment = $R_{TOT}/99$.

7. Typical values are for $T_A = +25°C$ and nominal supply voltage.
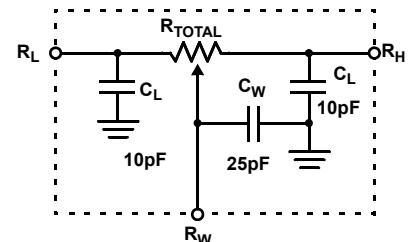
8. This parameter is not 100% tested.

Test Circuit #1
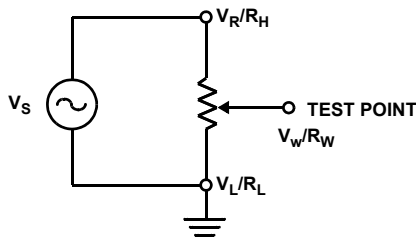
Test Circuit #2
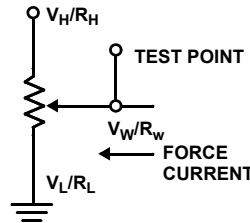
Circuit #3 SPICE Macro Model

Endurance and Data Retention

PARAMETER	MIN	UNIT
Medium Endurance	100,000	Data changes per bit per register
Data Retention	100	years

AC Conditions of Test

|	
Input Pulse Levels	0V to 3V
Input Rise and Fall Times	10ns
Input Reference Levels	1.5V

Power-up and Down Requirements

At all times, voltages on the potentiometer pins must be less than ±V_{CC}. The recall of the wiper position from non-volatile memory is not in effect until the V_{CC} supply reaches its final value. The V_{CC} ramp rate specification is always in effect.

RENESAS

AC Timing Diagram
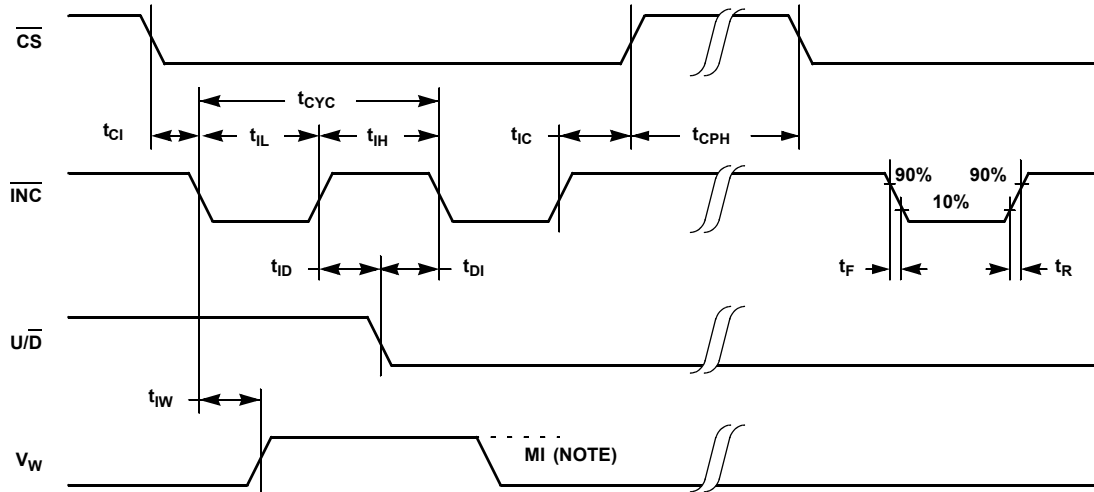
NOTE: MI REFERS TO THE MINIMUM INCREMENTAL CHANGE IN THE V_W OUTPUT DUE TO A CHANGE IN THE WIPER POSITION.

Pin Descriptions

R_H/V_H and R_L/V_L

The high (V_H/R_H) and low (V_L/R_L) terminals of the ISLX9C102, X9C103, X9C104, X9C503 are equivalent to the fixed terminals of a mechanical potentiometer. The minimum voltage is -5V and the maximum is +5V. The terminology of V_H/R_H and V_L/R_L references the relative position of the terminal in relation to wiper movement direction selected by the U/$\overline{D}$ input and not the voltage potential on the terminal.

R_W/V_W

V_W/R_W is the wiper terminal, and is equivalent to the movable terminal of a mechanical potentiometer. The position of the wiper within the array is determined by the control inputs. The wiper terminal series resistance is typically 40Ω.

Up/Down (U/$\overline{D}$)

The U/$\overline{D}$ input controls the direction of the wiper movement and whether the counter is incremented or decremented.

Increment ($\overline{INC}$)

The $\overline{INC}$ input is negative-edge triggered. Toggling $\overline{INC}$ will move the wiper and either increment or decrement the counter in the direction indicated by the logic level on the U/$\overline{D}$ input.

Chip Select ($\overline{CS}$)

The device is selected when the $\overline{CS}$ input is LOW. The current counter value is stored in non-volatile memory when $\overline{CS}$ is returned HIGH while the $\overline{INC}$ input is also HIGH. After the store operation is complete the ISLX9C102, X9C103, X9C104, X9C503 device will be placed in the low power standby mode until the device is selected once again.

Principles of Operation

There are three sections of the X9C102, X9C103, ISL9C104 and ISL9C503: the input control, counter and decode section; the non-volatile memory; and the resistor array. The input control section operates just like an up/down counter. The output of this counter is decoded to turn on a single electronic switch connecting a point on the resistor array to the wiper output. Under the proper conditions, the contents of the counter can be stored in non-volatile memory and retained for future use. The resistor array is comprised of 99 individual resistors connected in series. At either end of the array and between each resistor is an electronic switch that transfers the potential at that point to the wiper.

The wiper, when at either fixed terminal, acts like its mechanical equivalent and does not move beyond the last position. That is, the counter does not wrap around when clocked to either extreme.

The electronic switches on the device operate in a "make-before-break" mode when the wiper changes tap positions. If the wiper is moved several positions, multiple taps are connected to the wiper for t_{IW} ($\overline{INC}$ to V_W/R_W change). The R_{TOTAL} value for the device can temporarily be reduced by a significant amount if the wiper is moved several positions.

When the device is powered-down, the last wiper position stored will be maintained in the non-volatile memory. When power is restored, the contents of the memory are recalled and the wiper is reset to the value last stored.

The internal charge pump allows a wide range of voltages (from -5V to 5V) applied to XDCP terminals yet given a convenience of single power supply. The typical charge pump noise of 20mV at 850kHz should be taken in consideration when designing an application circuit.

Instructions and Programming

The INC, U/D and CS inputs control the movement of the wiper along the resistor array. With CS set LOW, the device is selected and enabled to respond to the U/D and INC inputs. HIGH to LOW transitions on INC will increment or decrement (depending on the state of the U/D input) a 7-bit counter. The output of this counter is decoded to select one of one-hundred wiper positions along the resistive array.

The value of the counter is stored in non-volatile memory whenever CS transitions HIGH while the INC input is also HIGH.

The system may select the X9Cxxx, move the wiper and deselect the device without having to store the latest wiper position in non-volatile memory. After the wiper movement is performed as previously described and once the new position is reached, the system must keep INC LOW while taking CS HIGH. The new wiper position will be maintained until changed by the system or until a power-down/up cycle recalled the previously stored data.

This procedure allows the system to always power-up to a pre-set value stored in non-volatile memory; then during system operation, minor adjustments could be made. The adjustments might be based on user preference, i.e.: system parameter changes due to temperature drift, etc.

The state of U/D may be changed while CS remains LOW. This allows the host system to enable the device and then move the wiper up and down until the proper trim is attained.

Mode Selection

CS	INC	U/D	MODE
L	⬎	H	Wiper Up
L	⬎	L	Wiper Down
⬏	H	X	Store Wiper Position
H	X	X	Standby Current
⬏	L	X	No Store, Return to Standby
⬎	L	H	Wiper Up (not recommended)
⬎	L	L	Wiper Down (not recommended)

Symbol Table

| WAVEFORM	INPUTS	OUTPUTS
‾‾‾‾‾	Must be steady	Will be steady
⟋⟋⟋	May change from Low to High	Will change from Low to High
⟍⟍⟍	May change from High to Low	Will change from High to Low
⟩⟨⟩⟨	Don't Care: Changes Allowed	Changing: State Not Known
⟩⟨⟩⟨	N/A	Center Line is High Impedance

Performance Characteristics

Contact the factory for more information.

Applications Information

Electronic digitally controlled (XCDP) potentiometers provide three powerful application advantages:

1. The variability and reliability of a solid-state potentiometer.
2. The flexibility of computer-based digital controls.
3. The retentivity of non-volatile memory used for the storage of multiple potentiometer settings or data.

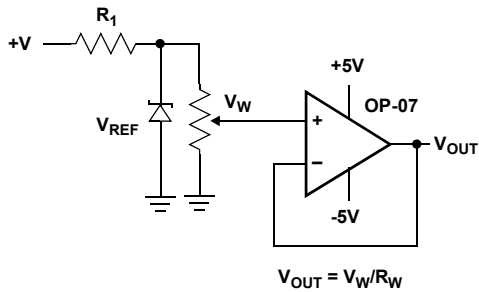### *Basic Configurations of Electronic Potentiometers*
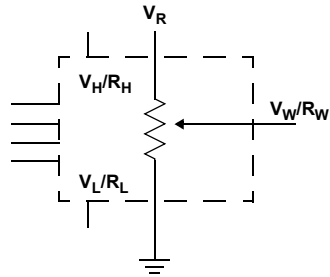
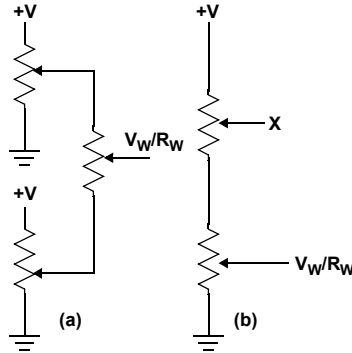THREE TERMINAL POTENTIOMETER;
VARIABLE VOLTAGE DIVIDER
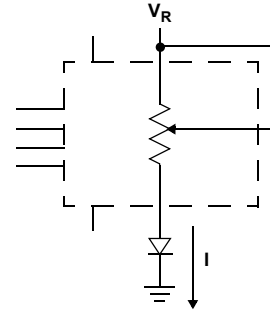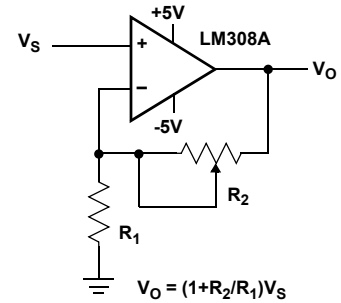
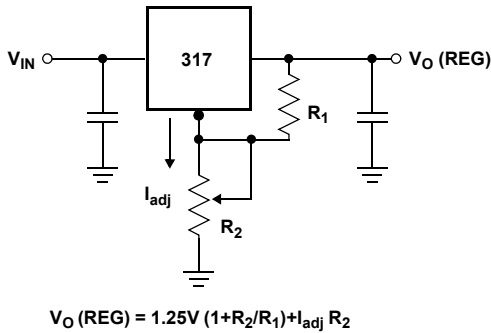TWO TERMINAL VARIABLE RESISTOR;
VARIABLE CURRENT

Basic Circuits

$V_{OUT} = V_W/R_W$

BUFFERED REFERENCE VOLTAGE

(a) (b)

CASCADING TECHNIQUES

$V_O = (1+R_2/R_1)V_S$

NONINVERTING AMPLIFIER

$V_O (REG) = 1.25V (1+R_2/R_1)+I_{adj} R_2$

VOLTAGE REGULATOR
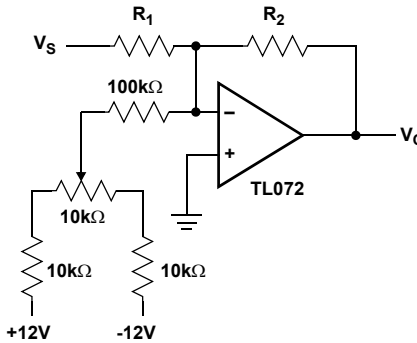
OFFSET VOLTAGE ADJUSTMENT

$V_{UL} = \{R_1/(R_1 + R_2)\} V_O(MAX)$
$V_{LL} = \{R_1/(R_1 + R_2)\} V_O(MIN)$
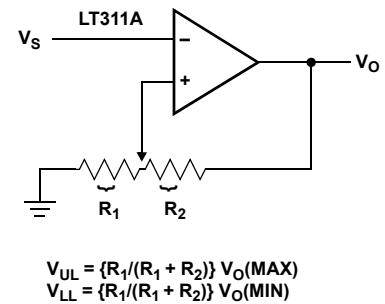
(FOR ADDITIONAL CIRCUITS SEE AN1145)

COMPARATOR WITH HYSTERESIS

Revision History

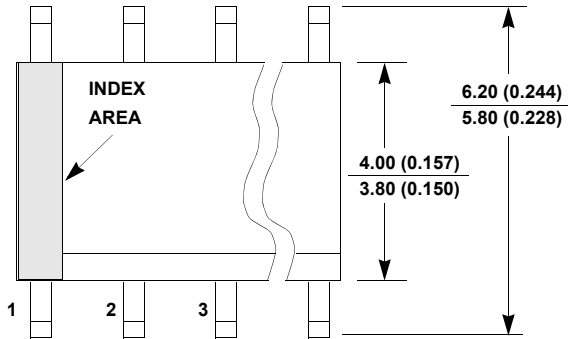| Rev.	Date	Description
4.00	Jan 11, 2019	Updated Ordering Information table to remove Obsolete and Retired parts. Added Revision History. Updated PODs for X9C102, X9C104, and X9C503 SOICs from: MDP0027 to: M8.15E and X9C103 SOIC from: MDP0027 to: M8.15, to include the Land Pattern design and convert dimensions from table to graphics. Updated Intersil disclaimer to Renesas disclaimer.

Package Outline Drawings

M8.15
8 LEAD NARROW BODY SMALL OUTLINE PLASTIC PACKAGE
Rev 4, 1/12

DETAIL "A"

1.27 (0.050)
0.40 (0.016)

0.50 (0.20)
0.25 (0.01) x 45°

8°
0°

0.25 (0.010)
0.19 (0.008)

SIDE VIEW "B"

INDEX
AREA

6.20 (0.244)
5.80 (0.228)

4.00 (0.157)
3.80 (0.150)

1   2   3

TOP VIEW

5.00 (0.197)
4.80 (0.189)

1.75 (0.069)
1.35 (0.053)

SEATING PLANE

-C-

1.27 (0.050)

0.25 (0.010)
0.10 (0.004)

0.51 (0.020)
0.33 (0.013)

SIDE VIEW "A

2.20 (0.087)

1   8

2   7

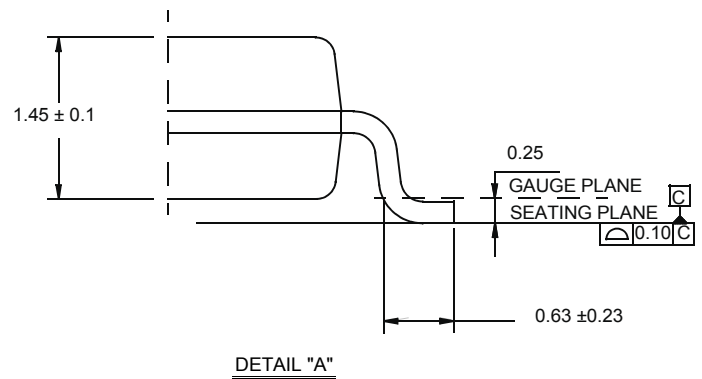3   6

4   5

0.60 (0.023)
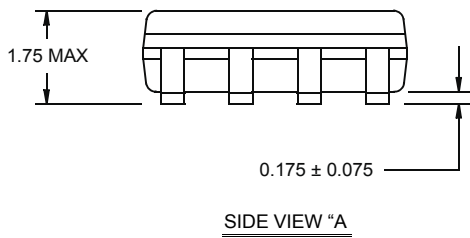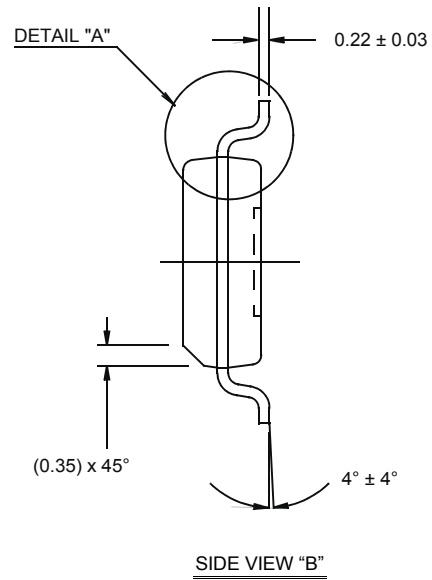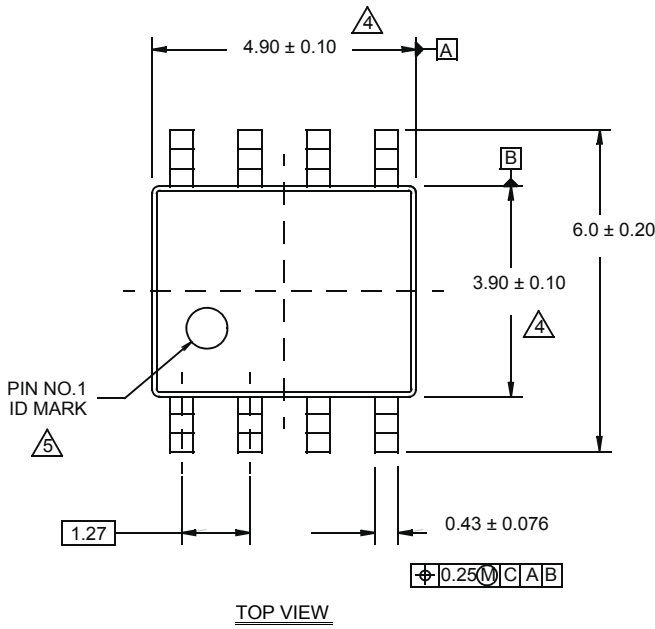
1.27 (0.050)

5.20 (0.205)
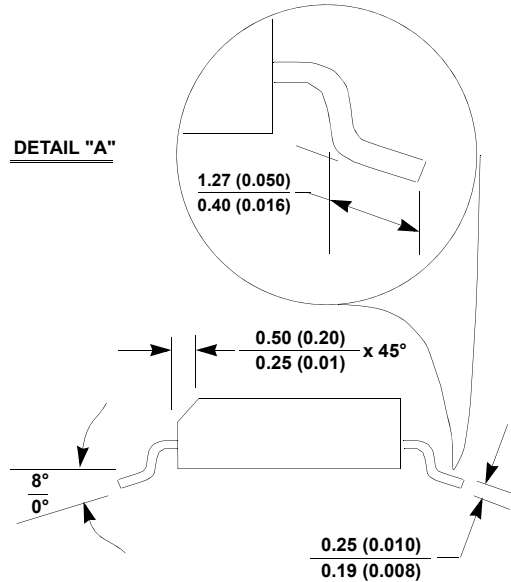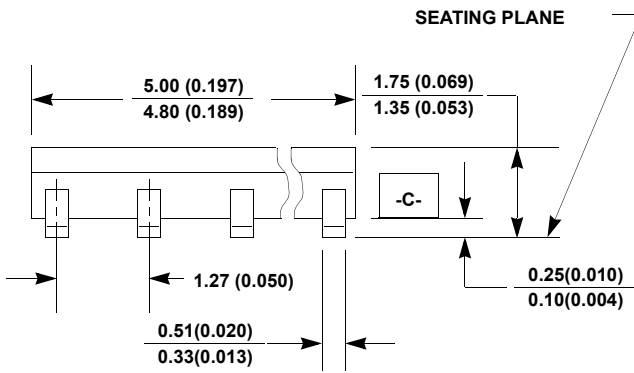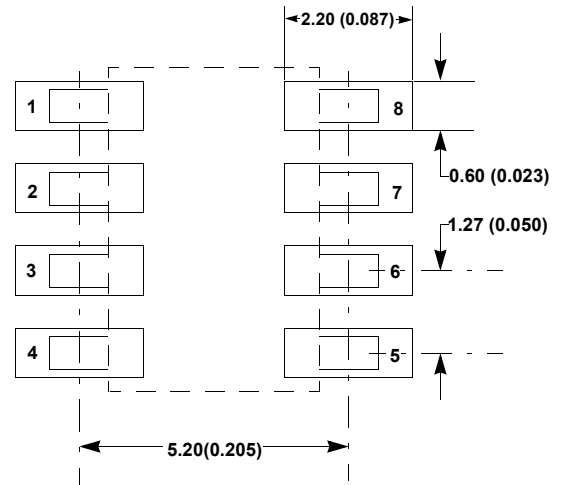
TYPICAL RECOMMENDED LAND PATTERN

NOTES:
9. Dimensioning and tolerancing per ANSI Y14.5M-1994.
10. Package length does not include mold flash, protrusions or gate burrs.
    Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
11. Package width does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side.
12. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
13. Terminal numbers are shown for reference only.
14. The lead width as measured 0.36mm (0.014 inch) or greater above the seating plane, shall not exceed a maximum value of 0.61mm (0.024 inch).
15. Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.
16. This outline conforms to JEDEC publication MS-012-AA ISSUE C.

RENESAS

M8.15E
8 LEAD NARROW BODY SMALL OUTLINE PLASTIC PACKAGE
Rev 0, 08/09

For the most recent package outline drawing, see M8.15E.

4.90 ± 0.10

6.0 ± 0.20

3.90 ± 0.10

PIN NO.1
ID MARK

1.27

0.43 ± 0.076

0.25 (M) C A B

TOP VIEW

DETAIL "A"

0.22 ± 0.03

(0.35) x 45°

4° ± 4°

SIDE VIEW "B"

1.75 MAX

0.175 ± 0.075

SIDE VIEW "A"

1.45 ± 0.1

0.25
GAUGE PLANE
SEATING PLANE

0.10 C

0.63 ±0.23

DETAIL "A"

(1.27)

(0.60)

(1.50)

(5.40)

TYPICAL RECOMMENDED LAND PATTERN
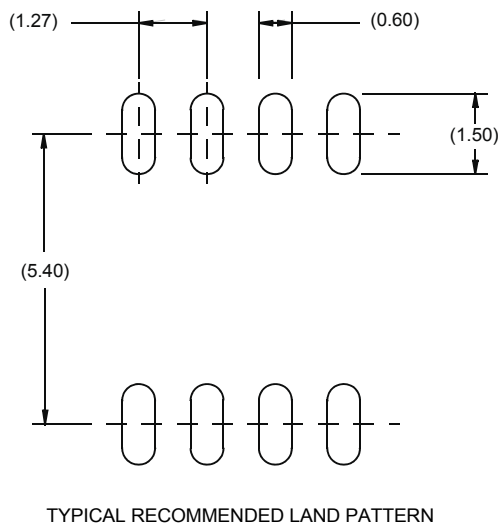
NOTES:

1. Dimensions are in millimeters.
   Dimensions in ( ) for Reference Only.

2. Dimensioning and tolerancing conform to AMSE Y14.5m-1994.

3. Unless otherwise specified, tolerance : Decimal ± 0.05

4. Dimension does not include interlead flash or protrusions.
   Interlead flash or protrusions shall not exceed 0.25mm per side.

5. The pin #1 identifier may be either a mold or mark feature.

6. Reference to JEDEC MS-012.

RENESAS

Plastic Dual-In-Line Packages (PDIP)

For the most recent package outline drawing, see .
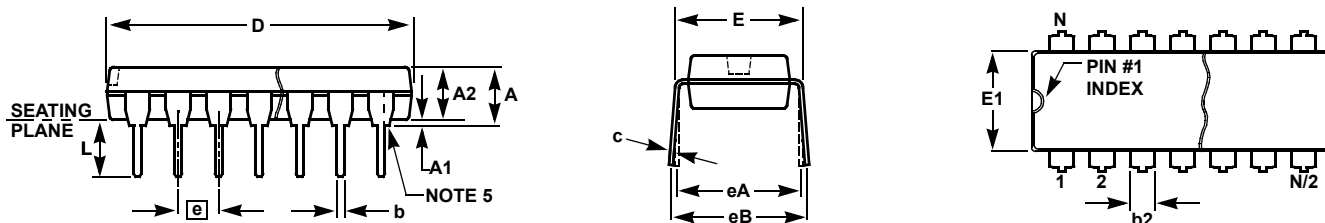
MDP0031
PLASTIC DUAL-IN-LINE PACKAGE

SYMBOL	INCHES					TOLERANCE	NOTES
	PDIP8	PDIP14	PDIP16	PDIP18	PDIP20		
A	0.210	0.210	0.210	0.210	0.210	MAX	
A1	0.015	0.015	0.015	0.015	0.015	MIN	
A2	0.130	0.130	0.130	0.130	0.130	±0.005	
b	0.018	0.018	0.018	0.018	0.018	±0.002	
b2	0.060	0.060	0.060	0.060	0.060	+0.010/-0.015	
c	0.010	0.010	0.010	0.010	0.010	+0.004/-0.002	
D	0.375	0.750	0.750	0.890	1.020	±0.010	1
E	0.310	0.310	0.310	0.310	0.310	+0.015/-0.010	
E1	0.250	0.250	0.250	0.250	0.250	±0.005	2
e	0.100	0.100	0.100	0.100	0.100	Basic	
eA	0.300	0.300	0.300	0.300	0.300	Basic	
eB	0.345	0.345	0.345	0.345	0.345	±0.025	
L	0.125	0.125	0.125	0.125	0.125	±0.010	
N	8	14	16	18	20	Reference	

Rev. C 2/07

NOTES:

17. Plastic or metal protrusions of 0.010" maximum per side are not included.

18. Plastic interlead protrusions of 0.010" maximum per side are not included.

19. Dimensions E and eA are measured with the leads constrained perpendicular to the seating plane.

20. Dimension eB is measured with the lead tips unconstrained.

21. 8 and 16 lead packages have half end-leads as shown.